

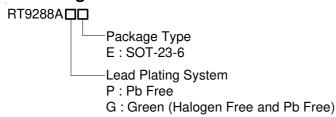
# PWM Step-Up DC/DC Controller for White-LED Driver

## **General Description**

The RT9288A is a wide input operating voltage range stepup controller. High voltage output and large output current are feasible by using an external N-MOSFET. The RT9288A input operating range is from 3V to 13.5V. Besides, it could support up to 60V output at 12V input.

The RT9288A is an optimized design for WLED driver applications. Adjusting the output current of the RT9288A changes the brightness of the WLEDs. Chip Enable pin can be used as a digital input allowing WLED brightness control with a logic-level PWM signal.

## **Ordering Information**



#### Note:

Richtek products are:

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- ▶ Suitable for use in SnPb or Pb-free soldering processes.

# **Marking Information**

For marking information, contact our sales representative directly or through a Richtek distributor located in your area.

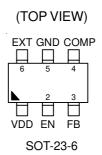
## **Features**

- V<sub>IN</sub> Operating Range : 3V to 13.5V
- Fixed PWM Frequency : 1MHz
- 200Hz to 200kHz PWM Dimming Frequency
- Flexible PWM/Analog Dimming Control
- Voltage Mode with External Compensation
- Soft Start Function
- RoHS Compliant and 100% Lead (Pb)-Free

# **Applications**

- TFT LCD Panels
- LED Backlighting

# **Pin Configurations**



## **Functional Pin Description**

Pin No.	Pin Name	Pin Function
1	VDD	Supply Input Voltage Pin. Bypass an 1uF capacitor to GND to reduce the input noise.
2	EN	Chip Enable (Active High).
3	FB	Feedback to Error Amplifier Input.
4	COMP	Output of Error Amplifier. Connect a capacitor between the COMP pin and GND for compensation. While shutdown, this pin is pulled down by an internal resistor.
5	GND	Ground Pin.
6	EXT	Output for External Transistor.



# **Typical Application Circuit**

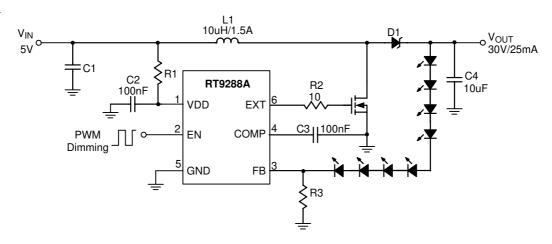


Figure 1. LED Driver with PWM Brightness Control (5V → 30V)

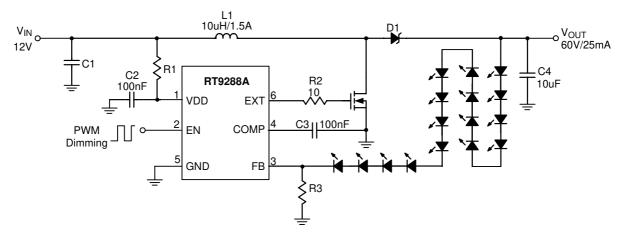


Figure 2. LED Driver with PWM Brightness Control (12V → 60V)

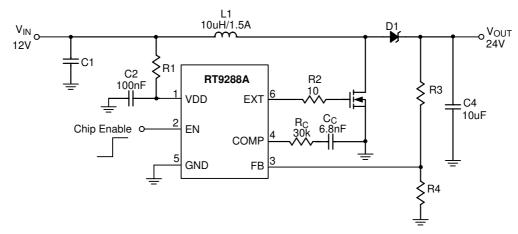
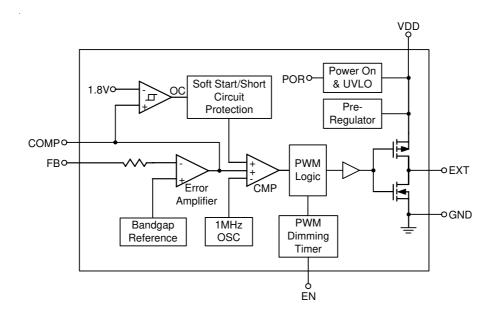


Figure 3. Application for Constant Output Voltage

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## **Function Block Diagram**



# **Operation**

### **Soft-Start and Short Circuit Protection**

While power-on, the RT9288A enters soft-start cycle to reduce the in-rush current and output voltage overshoot. The internal soft-start time is 10ms for the RT9288A. The RT9288A enters shutdown and can be re-enabled by turning off-on EN pin.

In normal operation, if the output loading changes large enough to let error amplifier output larger than 1.8V, the short circuit timer is started. If the time duration of this condition is kept continuously to more than *10ms*, the short circuit state is latched and the RT9288 enters shutdown and can be re-enabled by turning off-on EN pin.

### **Dimming Control for LED Lighting**

EN is also used as a digital input allowing LED brightness control with a logic-level PWM signal applied directly to EN. The frequency range is from 200Hz to 200kHz, while 0% duty cycle corresponds to zero current and 100% duty cycle corresponds to full current. The error amplifier and compensation capacitor form a lowpass filter, so the PWM dimming results in DC current to the LEDs without any additional RC filters. The PWM signal must be applied after soft-start finished.

### **Under-Voltage Lock-out**

The under voltage lock-out circuit is adopted as a voltage detector and always monitors the supply voltage ( $V_{DD}$ ) while EN at logic High. While power-on, the chip is kept in shutdown mode till the  $V_{DD}$  rises to higher than 2.5V (MAX). While power-off, the chip does not leave operating mode till  $V_{DD}$  falls to less than 2.2V(MIN).



# Absolute Maximum Ratings (Note 1)

Supply Input Voltage, V <sub>DD</sub>	
• EN, EXT Pins	$-0.3V$ to $V_{DD} + 0.3V$
• FB, COMP Pins	
<ul> <li>Power Dissipation, P<sub>D</sub> @ T<sub>A</sub> = 25°C</li> </ul>	
SOT-23-6	0.455W
Package Thermal Resistance (Note 2)	
SOT-23-6, θ <sub>JA</sub>	220°C/W
Lead Temperature (Soldering, 10 sec.)	260°C
Junction Temperature	150°C
Storage Temperature Range	
ESD Susceptibility (Note 3)	
HBM (Human Body Mode)	2kV
MM (Machine Mode)	200V
Recommended Operating Conditions (Note 4)	
Supply Input Voltage, V <sub>DD</sub>	3V to 13.5V
Junction Temperature Range	
•	

## **Electrical Characteristics**

 $(V_{DD} = 5V, T_A = 25^{\circ}C, unless otherwise specified)$ 

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Power-On Reset							
Operating Supply Voltage Range	$V_{DD}$	Normal operation	3	5	13.5	V	
Under Voltage Lock Out	UVLO	V <sub>DD</sub> Rising	2.2		2.5	V	
Supply current in PWM Mode	I <sub>PWM</sub>	$V_{FB} = V_{REF} + 0.1V$		2		mA	
Shutdown Current	I <sub>SHDN</sub>	$V_{EN} = 0V$		1	10	uA	
Sawtooth Generator							
Oscillation Frequency	f <sub>OSC</sub>		0.8	1	1.2	MHz	
Frequency Stability		V <sub>DD</sub> = 3V to 13.5V		2	10	%	
Maximum Duty Cycle			85	90	95	%	
Error Amplifier	•	•	•	•		•	
Trans-Conductance	GM			60		uA/V	
Feedback Voltage	$V_{FB}$			0.5		V	
Feedback Line Regulation		$V_{DD} = 3V \text{ to } 13.5V$		5		mV	
Maximum Output Voltage	V <sub>FB_MAX</sub>	$V_{COMP} = V_{FB} = low$		2.4		V	
Minimum Output Voltage	V <sub>FB_MIN</sub>	V <sub>COMP</sub> = V <sub>FB</sub> = high		0.05		V	
Output Source Current		$V_{COMP} = 0.7V$ , $V_{FB} = low$		20		uA	
Output Sink Current		$V_{COMP} = 0.7V$ , $V_{FB} = high$		20		uA	
Soft Start & Short Circuit Unit							
Soft-Start Ramp Time			5	10	20	ms	

To be continued

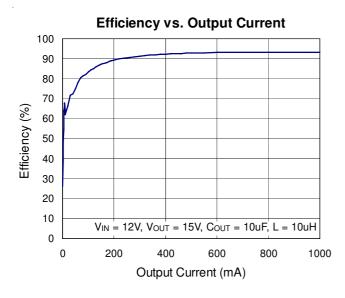


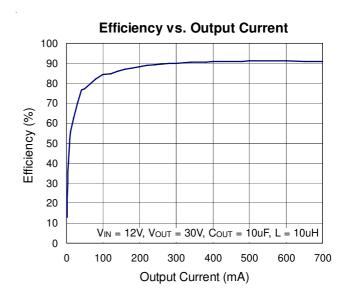
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Output driver						
On Resistance (P-MOSFET)	R <sub>DS(ON)</sub> P			30	60	Ω
On Resistance (N-MOSFET)	R <sub>DS(ON)_N</sub>			20	40	Ω
Output rising/falling time (Note 5)		$C_L = 1000pF, V_{FB} = Low$		100		ns
Logic						
EN Pin Low Voltage	V <sub>IL</sub>				0.5	V
EN Pin High Voltage	V <sub>IH</sub>		1.8		V <sub>DD</sub>	V

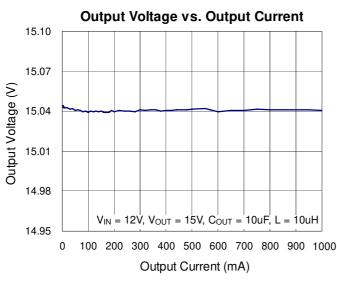
- **Note 1.** Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.
- Note 2.  $\theta_{JA}$  is measured in the natural convection at  $T_A = 25^{\circ}C$  on a low effective thermal conductivity test board of JEDEC 51-3 thermal measurement standard.
- Note 3. Devices are ESD sensitive. Handling precaution is recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.
- Note 5. Guarantee by design.

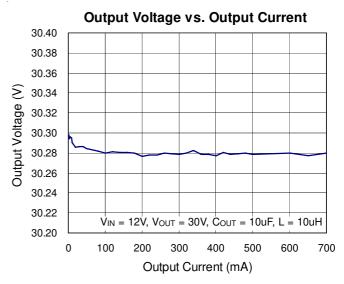


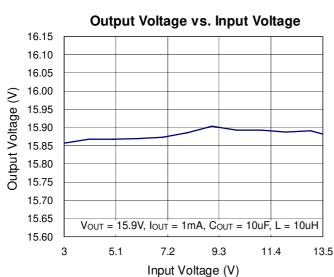
# **Typical Operating Characteristics**

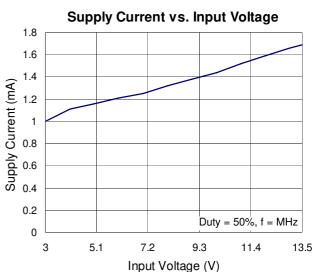




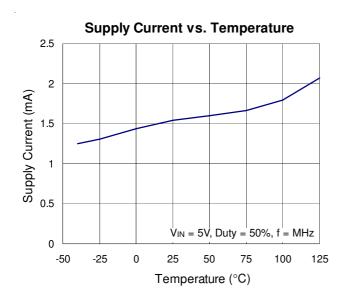


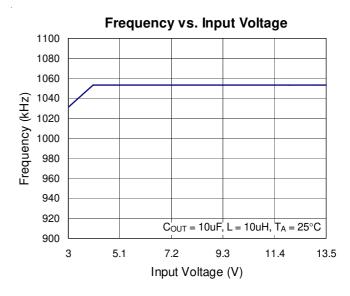


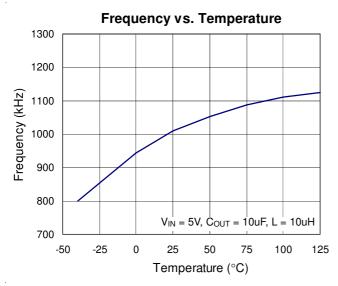


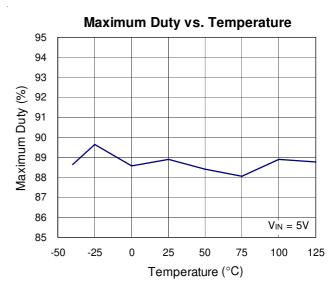


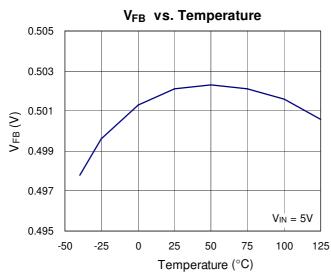


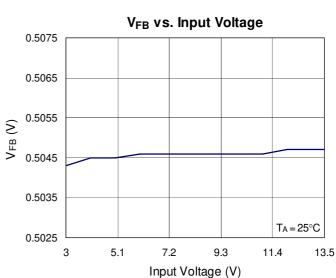








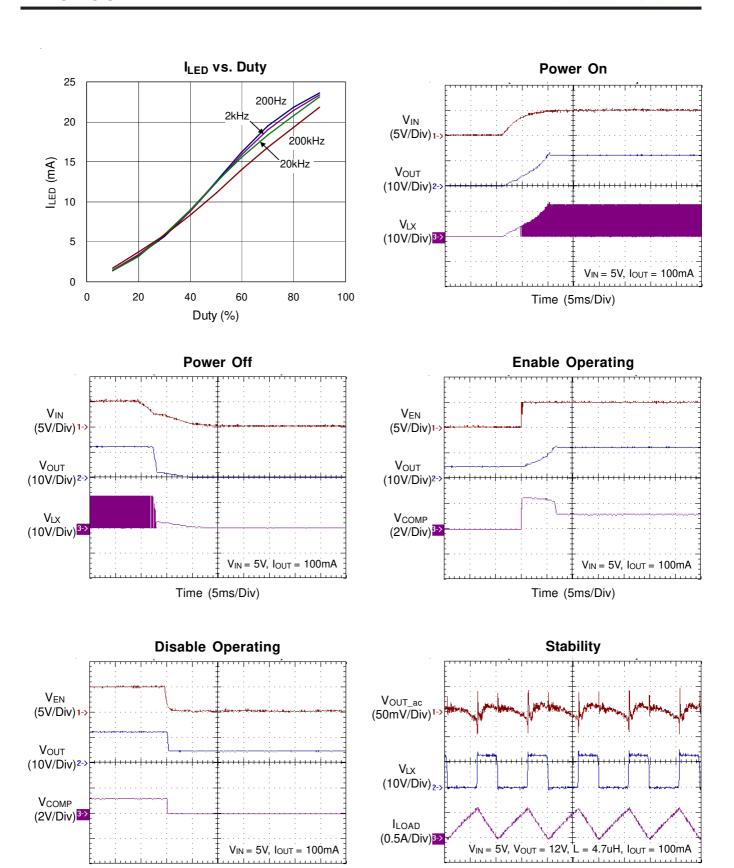




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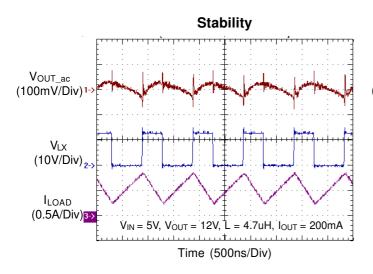


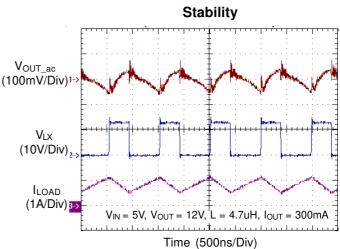


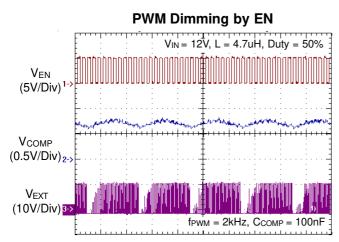
Time (500ns/Div)

Time (5ms/Div)









Time (2.5ms/Div)



# **Application Information**

The RT9288A is a boost controller for DC to DC conversion. The main switch of the power stage can stand significant current that is greater than the internal main switch. There is no significant power dissipated in the RT9288A, therefore the thermal performance could be excellent. For the RT9288A, determine the maximum input current is the first step of the design procedure.

#### **Inductor Selection**

For the inductor selection, the inductance value depends on the maximum input current. Generally the inductor ripple current range is 20% to 40% of the maximum input current. Take 40% as an example, the value can be calculated as follows:

$$I_{IN(MAX)} = \frac{V_{OUT} \times I_{OUT(MAX)}}{n \times V_{IN}}$$
 (1)

$$I_{RIPPLE} = 0.4 \times I_{IN(MAX)} \tag{2}$$

Where  $\eta$  is the efficiency,  $I_{\text{IN(MAX)}}$  is the maximum input current and  $I_{\text{RIPPLE}}$  is the inductor ripple current. Beside, the input peak current is the maximum input current plus half of the inductor ripple current.

$$I_{PEAK} = 1.2 \times I_{IN(MAX)} \tag{3}$$

Note that the saturated current of inductor must be greater than  $I_{PEAK}$ . The inductance value can be eventually determined as follows:

$$L = \frac{\eta \times (V_{IN})^2 \times (V_{OUT} - V_{IN})}{0.4 \times (V_{OUT})^2 \times I_{OUT(MAX)} \times f_{OSC}}$$
(4)

Where  $f_{OSC}$  is the switching frequency. Consider the system performance, a shielded inductor is preferred to avoid EMI issue.

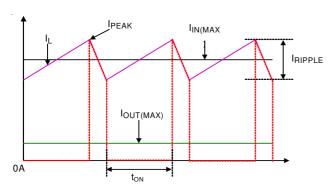


Figure 4. The Waveform of the Inductor Current

#### **Diode Selection**

Schottky diode is a good choice for an asynchronous Boost converter due to the small forward voltage. However, power dissipation, reverse voltage rating and pulsating peak current are the important parameters of Schottky diode consideration. It is recommended to choose a suitable diode whose reverse voltage rating is greater than the maximum output voltage.

## **Input Capacitor Selection**

Low ESR ceramic capacitors are recommended for input capacitor applications. Low ESR will effectively reduce the input ripple voltage caused by switching operation. A 10uF is sufficient for most applications. Nevertheless, this value can be decreased with lower output current requirement. Another consideration is the voltage rating of input capacitor must be greater than the maximum input voltage.

## **Output Capacitor Selection**

Output ripple voltage is an important index for estimating the performance. This portion consists of two parts, one is the product of ( $I_{IN}-I_{OUT}$ ) and ESR of the output capacitor, another part is formed by charging and discharging process of output capacitor. Refer to figure 5, evaluate  $\Delta V_{OUT1}$  by ideal energy equalization. According to the definition of Q that is calculated as follows :

$$Q = \frac{1}{2} \times \left[ \left( I_{IN} + \frac{1}{2} \Delta I_{L} - I_{OUT} \right) + \left( I_{IN} - \frac{1}{2} \Delta I_{L} - I_{OUT} \right) \right]$$

$$\times \frac{V_{IN}}{V_{OUT}} \times \frac{1}{f_{OSC}} = C_{OUT} \times \Delta V_{OUT1}$$
(5)

Where  $T_S$  is the inverse of switching frequency and the  $\Delta I_L$  is the inductor ripple current. Move  $C_{OUT}$  to left side to estimate the value of  $\Delta V_{OUT1}$  as :

$$\Delta V_{OUT1} = \frac{D \times I_{OUT}}{\eta \times C_{OUT} \times f_{OSC}}$$
 (6)

Finally, the output ripple voltage can be determined as :

$$\Delta V_{OUT} = (I_{IN} - I_{OUT}) \times ESR + \frac{D \times I_{OUT}}{\eta \times C_{OUT} \times f_{OSC}}$$
(7)

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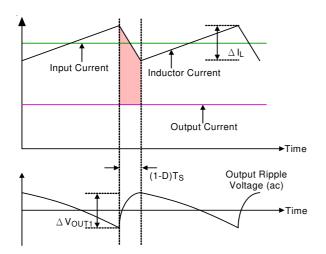


Figure 5. The Output Ripple Voltage without the Contribution of ESR

#### Main Switch Selection

The RT9288A uses an N-MOSFET as the main switch to achieve power conversion. The main switch stays in two states in the operation, one is the on state and the other is the off state. The potential of switching point, LX, is 0V in the on state. Nevertheless, the potential of LX rises to output voltage plus the forward voltage of D, in the off state, this potential is the highest voltage in the Boost converter. Thus, the absolute V<sub>DS</sub> rating of the main switch must be greater than this voltage to prevent main switch damage in the off state or reliability problem. Another key parameter of main switch is the maximum continuous drain current. For a safety design, it is important to choose a maximum continuous drain current at two times the maximum input current. Energy saving is the trend in recent years. Therefore, design a high efficiency system is the important course. Conduction loss and switching loss play important roles for the efficiency in heavy load and light load respectively. Main switch with a small on resistance leads to lower conduction loss, however, it also means a greater gate capacitance. Great gate capacitance prolongs rising and falling transition in LX, t<sub>1</sub> and t<sub>2</sub>. I<sub>L</sub> and  $V_{LX}$  produce the main switching loss during  $t_1$  and  $t_2$ . Thus, choose a main switch with proper gate capacitance could reduce switching loss.

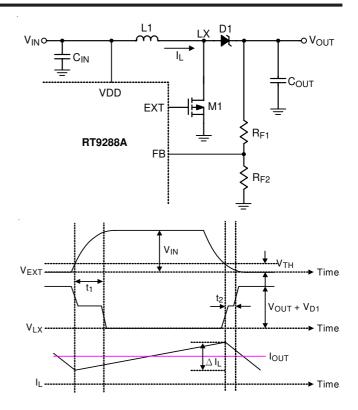


Figure 6. The Waveforms of EXT, LX and Inductor Current Related to the Switching Loss

#### **Loop Compensation**

It is easy to compensate the loop stability for the RT9288A's application in LED driving. Compensation network only contains a capacitor between COMP pin and GND as shown in figure 1. The best criterion to optimize the loop compensation is by inspecting the transient response and adjusting the compensation network.

### **Layout Consideration**

The PCB layout is a very important issue for switching converter circuits design. There are some recommended layout guidelines that are shown as follows:

- ▶ The power components M1, L1, D1, C<sub>IN</sub> and C<sub>OUT</sub> should be placed as close to the IC as possible to reduce the ac current loop. The connections between power components must be short and wide as possible due to large current stream flowing through these traces during operation.
- ▶ The function of C1 is to regulate V<sub>DD</sub>. Place C1 close to pin 1 is necessary.



- ▶ R<sub>F1</sub> and R<sub>F2</sub> formed a voltage divider to set correct output voltage. Pin 3 is connected to the branch of voltage divider and is a very sensitive point, placed this trace short and wide as possibly and far away from the switching point to avoid perturbation.
- ▶ Pin 4 is the compensation point for system stability. Place the compensation components as close to pin 4 as possibly, no matter the compensation is R<sub>C</sub> or capacitance. Note that, the GND of the compensation components should be connected with pin 5. Then, short it to system ground by via or trace. This will provide a clean reference for the IC.

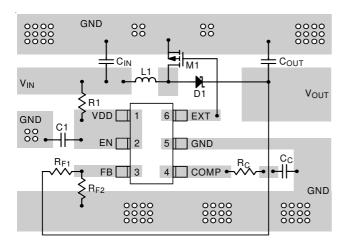
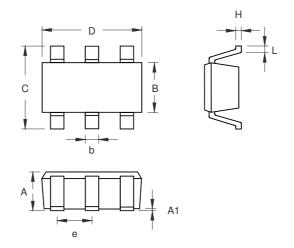


Figure 7. Sketch Map of PCB Layout.



## **Outline Dimension**



Cumahal	Dimensions I	n Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
Α	0.889	1.295	0.031	0.051		
A1	0.000	0.152	0.000	0.006		
В	1.397	1.803	0.055	0.071		
b	0.250	0.560	0.010	0.022		
С	2.591	2.997	0.102	0.118		
D	2.692	3.099	0.106	0.122		
е	0.838	1.041	0.033	0.041		
Н	0.080	0.254	0.003	0.010		
L	0.300	0.610	0.012	0.024		

**SOT-23-6 Surface Mount Package** 

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